

Ge ACOUSTO-OPTIC MODULATOR

Germanium AOM for High-Power, 5.5 µm Applications

PRODUCT DATASHEET

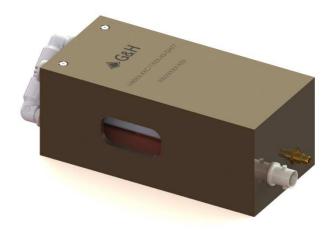
An acousto-optic modulator for use at 5.5 µm wavelength, ideal for extracavity modulation or power control of high power CO lasers.

Combining optimum grade mono-crystalline germanium, high quality optical finishing, robust anti-reflection coating and high reliability transducer bonding, with novel acoustic management and opto-mechanical design techniques, we have successfully achieved exceptional thermal management whilst maintaining high RF power handling, transmission and diffraction efficiency.

In addition to the specifications indicated, we also offer alternative wavelengths, RF frequencies, active apertures and a wide range of custom housing configurations.

This product conforms to the requirements of the European Union Directive 2011/65/EU of the European Parliament and of the Council on the Restriction of the Use of Certain Hazardous Substances in Electrical and Electronic Equipment.

Our scientists and engineers are available to assist in selecting the most appropriate acousto-optic device and RF driver for your application.



Key Features

- High optical power handling
- Low insertion loss
- Excellent pointing stability
- Superior beam quality
- High diffraction efficiency

Applications

- Industrial (material processing)
 - Glass processing (cutting, drilling, welding)
 - PCB via drilling
 - Marking and engraving
 - Multi-layer polymer film cutting
 - Ceramic cutting and drilling

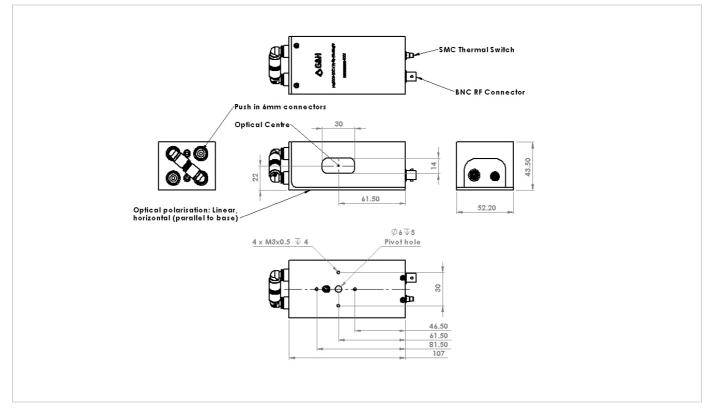
As part of our policy of continuous product improvement, we reserve the right to change specifications at any time.



General Specifications

Device:	AO Modulator
Interaction material:	Germanium
Wavelength:	5.5 µm
Maximum recommended optical power density:	30 W/mm ²
AR coating reflectivity:	$< 0.2\%$ per surface (< 0.5% - 5.25-5.75 $\mu m)$
Transmission:	> 98%
Frequency:	40.68 MHz
Optical polarization:	Linear, horizontal (parallel to base)
Active aperture:	9.6 mm
Acoustic mode:	Compressional
Rise-time (10-90%):	120 ns/mm
Separation angle:	41 mrad
Diffraction efficiency:	≥ 90%
RF Power:	Typ. 50 W
Housing:	Refer to drawing
Recommended RF Driver:	HP041-60ADG-A10

Device schematic



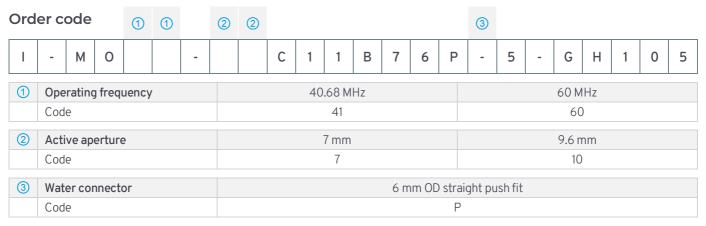
Ge ACOUSTO-OPTIC MODULATOR – I-M0XX-9.6C11B76-P5-GH105

Data sheet ref: IWDS053/Revision No. 1.4

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Ordering information



Also see Datasheet IWDS051 for details of our Ge-AOM's for 9.4 μ m and 10.6 μ m lasers.

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